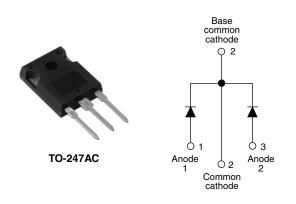
Vishay High Power Products

HEXFRED[®] Ultrafast Soft Recovery Diode, 2 x 16 A



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PRODUCT SUMMARY				
V _R per leg	1200 V			
V _F at 16 A at 25 °C	3.0 V			
I _{F(AV)}	2 x 16 A			
t _{rr} (typical) per leg	30 ns			
T _J (maximum)	150 °C			
Q _{rr} (typical) per leg	260 nC			
I _{RRM} (typical) per leg	5.8 A			

FEATURES

- Ultrafast recovery
- · Ultrasoft recovery
- Very low I_{RRM}
- Very low Q_{rr}
- Specified at operating conditions
- Lead (Pb)-free
- Designed and qualified for industrial level

BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION

HFA32PA120C is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 1200 V and 16 A per leg continuous current, the HFA32PA120C is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I_{RBM}) and does not exhibit any tendency to "snap-off" during the t_b portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA32PA120C is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Cathode to anode voltage	V _R		1200	V	
Maximum continuous forward currentper leg	١ _F	T _C = 100 °C	16		
per device			32	А	
Single pulse forward current	I _{FSM}		190	A	
Maximum repetitive forward current	I _{FRM}		64		
Maximum power dissipation	PD	T _C = 25 °C	151	°C	
		T _C = 100 °C	60		
Operating junction and storage temperature range	T _J , T _{Stg}		- 55 to + 150	W	

* Pb containing terminations are not RoHS compliant, exemptions may apply



COMPLIANT

HFA32PA120CPbF



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ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		1200	-	-	
		I _F = 16 A	See fig. 1	-	2.5	3.0	V
Maximum forward voltage V _{FM}	V _{FM}	I _F = 32 A		-	3.2	3.93	
		I _F = 16 A, T _J = 125 °C		-	2.3	2.7	
Maximum reverse		V _R = V _R rated	See fig. 0	-	0.75	20	
leakage current	e current I_{RM} $T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$ See fig. 2	See fig. 2	-	375	2000	μΑ	
Junction capacitance	CT	V _R = 200 V	See fig. 3	-	27	40	pF
Series inductance	L _S	Measured lead to lead 5 mm from package body - 8.0 -		nH			

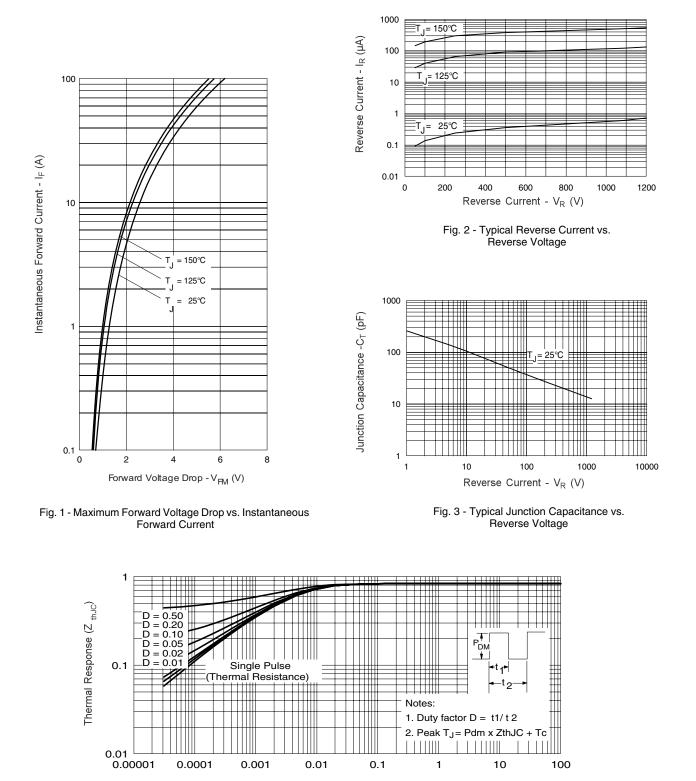
DYNAMIC RECOVERY CHARACTERISTICS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	t _{rr}	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	30	-	
Reverse recovery time See fig. 5, 10	t _{rr1}	T _J = 25 °C	I _F = 16 A dI _F /dt = 200 A/μs V _R = 200 V	-	90	135	ns
000 lig. 0, 10	t _{rr2}	T _J = 125 °C		-	164	245	
Peak recovery current	I _{RRM1}	T _J = 25 °C		-	5.8	10	А
See fig. 6	I _{RRM2}	T _J = 125 °C		-	8.3	15	
Reverse recovery charge	Q _{rr1}	T _J = 25 °C		-	260	675	nC
See fig. 7	Q _{rr2}	T _J = 125 °C		-	680	1838	10
Peak rate of fall of recovery	dl _{(rec)M} /dt1	T _J = 25 °C		-	120	-	A/μs
current during t _b See fig. 8	dl _{(rec)M} /dt2	$T_J = 125 \text{ °C}$	-	76	-	Λίμο	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T _{lead}	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R _{thJC}		-	-	0.83	
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	80	K/W
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.50	-	
W/sight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)
Marking device		Case style TO-247AC (JEDEC)	HFA32PA120C		•	

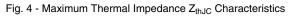


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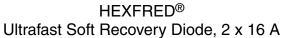


t₁, Rectangular Pulse Duration (sec)



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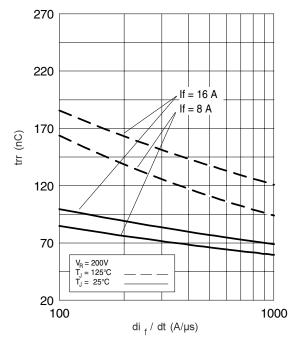


Fig. 5 - Typical Reverse Recovery Time vs. dI_F/dt (Per Leg)

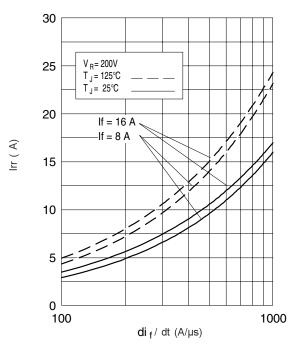
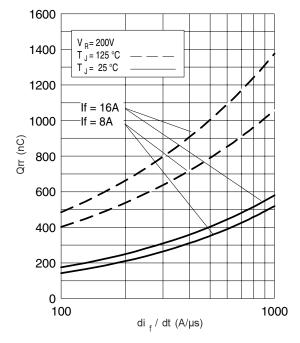


Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)



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Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

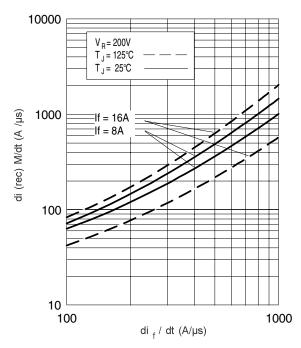


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt (Per Leg)



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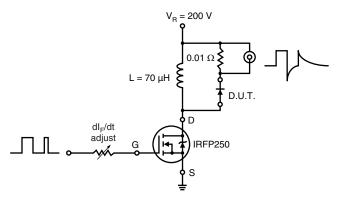


Fig. 9 - Reverse Recovery Parameter Test Circuit

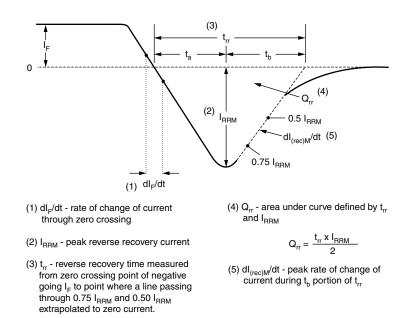


Fig. 10 - Reverse Recovery Waveform and Definitions

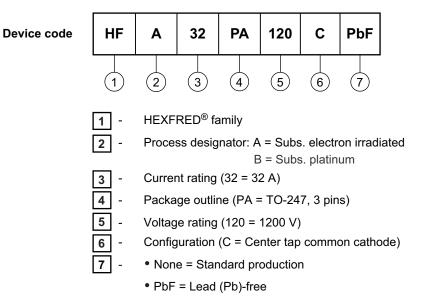
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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS					
Dimensions http://www.vishay.com/doc?95223					
Part marking information	http://www.vishay.com/doc?95226				



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